

HAC RF TESTREPORT

No. I18Z61787-SEM02

For

TCL Communication Ltd.

GSM/UMTS/LTE mobile phone

Model name: A503DL

With

Hardware Version: PIO

Software Version: vTV5

FCC ID: 2ACCJH096

Results Summary: M Category = M4

Issued Date: 2018-11-21



Note:

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REPORT HISTORY

Report Number	Revision	Issue Date	Description
I18Z61787-SEM02	Rev.0	2018-11-16	Initial creation of test report
I18Z61787-SEM02	Rev.1 2018-11-21 Update the		Update the report number in page header



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1 Test Laboratory

1.1 Testing Location

CompanyName:	CTTL(Shouxiang)
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,
	Beijing, P. R. China100191

1.2 Testing Environment

Temperature:	18°C~25°C,
Relative humidity:	30%~ 70%
Ground system resistance:	< 0.5 Ω

Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.

1.3 Project Data

Project Leader:	Qi Dianyuan
Test Engineer:	Lin Hao
Testing Start Date:	October 11, 2018
Testing End Date:	October 12, 2018

1.4 Signature

Lin Xiaojun

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

Lu Bingsong

Deputy Director of the laboratory

(Approved this test report)



2 Client Information

2.1 Applicant Information

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Fax:	0086-75536612000-81722	



3 Equipment Under Test (EUT) and Ancillary Equipment (AE)

3.1 About EUT

Description:	GSM/UMTS/LTE mobile phone
Model name: A503DL	
Operating mode(s):	GSM 850/900/1800/1900, UMTS FDD 2/4/5, BT, Wi-Fi
	LTE Band 2/4/5/12/13/66/71

3.2 Internal Identification of EUT used during the test

EUT ID*	IMEI	HW Version	SW Version
EUT1	015283000110531	PIO	vTV5
EUT2	015283000110416	PIO	vTV5
EUT3	015283000110507	PIO	vTV5
EUT4	015283000110432	PIO	vTV5

^{*}EUT ID: is used to identify the test sample in the lab internally.

Note: It is performed to test HAC with the EUT1 and conducted power with the EUT2-4.

3.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
AE1	Battery	CAC2900019C1	/	BYD

^{*}AE ID: is used to identify the test sample in the lab internally.

3.4 Air Interfaces / Bands Indicating Operating Modes

Air-interface	Band(MHz)	Туре	C63.19/tested	Simultaneous Transmissions	OTT
GSM	850	VO	Yes		
GSIVI	1900		res	DT M/L AND	NA
CDDC/EDCE	850	рт	NA	BT, WLAN	INA
GPRS/EDGE	1900	DT	INA		
	850				
WCDMA	1700	1700 VO Yes 1900		BT, WLAN NA	NΙΔ
(UMTS)	1900				INA
	HSPA	DT	NA		
LTE	Band 2/5/12/13/66/71	V/D	Yes	BT, WLAN	NA
ВТ	2450	DT	NA	GSM, WCDMA, LTE	NA
WLAN	2450	V/D	Yes	GSM, WCDMA, LTE	NA

VO: Voice CMRS/PSTN Service Only V/D: Voice CMRS/PSTN and Data Service DT: Digital Transport

^{*} HAC Rating was not based on concurrent voice and data modes, Non current mode was found to represent worst case rating for both M and T rating



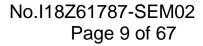
4 CONDUCTED OUTPUT POWER MEASUREMENT

4.1 Summary

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured output power should be greater and within 5% than EMI measurement.

4.2 Conducted Power

0014		Conducted Power (dBm)				
GSM 850MHz	Channel 251(848.8MHz)	Channel 190(836.6MHz)	Channel 128(824.2MHz)			
OSUMINZ	32.70	32.69	32.67			
GSM	Conducted Power(dBm)					
1900MHz	Channel 810(1909.8MHz)	Channel 661(1880MHz)	Channel 512(1850.2MHz)			
190011112	29.99	30.08	30.03			
WCDMA		Conducted Power (dBm)				
850MHz	Channel 4233(846.6MHz)	Channel 4182(836.4MHz)	Channel 4132(826.4MHz)			
03011112	22.83	22.38	22.77			
WCDMA		Conducted Power (dBm)				
1700MHz	Channel 1513 (1752.6MHz)	Channel 1412 (1732.4MHz)	Channel 1312 (1712.4MHz)			
1700MHZ	22.83	22.98	22.93			
WCDMA		Conducted Power (dBm)				
1900MHz	Channel 9538(1907.6MHz)	Channel 9400(1880MHz)	Channel 9262(1852.4MHz)			
1900141112	23.99	23.97	23.94			
LTE		Conducted Power (dBm)				
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)			
QPSK	23.68	23.43	23.33			
LTE		Conducted Power (dBm)				
Band5	Channel 20600(844MHz)	Channel 20525(836.5MHz)	Channel20450(829MHz)			
QPSK	23.39	23.42	23.41			
LTE		Conducted Power (dBm)				
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)			
QPSK	23.55	23.64	23.64			
LTE		Conducted Power (dBm)				
Band13		Channel 23230(782MHz)				
QPSK	23.19					
LTE	Conducted Power (dBm)					
Band66	Channel 132572(1770MHz)	Channel 132322(1745MHz)	Channel 132072(1720MHz)			
QPSK	23.67	23.73	23.87			
LTE		Conducted Power (dBm)				
Band71	Channel 133372 (688MHz)	Channel 133322 (683MHz)	Channel 133222(673MHz)			
QPSK	23.81	23.78	23.72			





LTE		Conducted Power (dBm)		
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)	
16-QAM	22.97	22.95	22.70	
LTE		Conducted Power (dBm)		
Band5	Channel 20600(844MHz)	Channel 20525(836.5MHz)	Channel20450(829MHz)	
16-QAM	22.63	22.59	22.59	
LTE		Conducted Power (dBm)		
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)	
16-QAM	22.80	22.76	22.84	
LTE	Conducted Power (dBm)			
Band13		Channel 23230(782MHz)		
16-QAM		22.07		
LTE		Conducted Power (dBm)		
Band66	Channel 132572(1770MHz)	Channel 132322(1745MHz)	Channel 132072(1720MHz)	
16-QAM	22.92	22.90	22.92	
LTE		Conducted Power (dBm)		
Band71	Channel 133372 (688MHz)	Channel 133322 (683MHz)	Channel 133222(673MHz)	
QPSK	22.91	22.92	22.84	
2.4GHz	Conducted Power (dBm)			
802.11b	Channel 11 (2462MHz)	Channel 6 (2437MHz)	Channel 1 (2412MHz)	
5.5M	18.91	20.47	20.33	



5 Reference Documents

5.1 Reference Documents for testing

The following document listed in this section is referred for testing.

The following document listed in this section is referred for testing.					
Reference	Title	Version			
ANSI C63.19-2011	American National Standard for Methods of Measurement of	2011			
	Compatibility between Wireless Communication Devices and	Edition			
	Hearing Aids				
FCC 47 CFR §20.19	Hearing Aid Compatible Mobile Headsets				
		Edition			
KDB 285076 D01	Equipment Authorization Guidance for Hearing Aid Compatibility				



6 OPERATIONAL CONDITIONS DURING TEST

6.1 HAC MEASUREMENT SET-UP

These measurements are performed using the DASY5 NEO automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and remote control, is used to drive the robot motors. The PC consists of the HP Intel Core21.86 GHz computer with Windows XP system and HAC Measurement Software DASY5 NEO, A/D interface card, monitor, mouse, and keyboard. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE)circuit performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

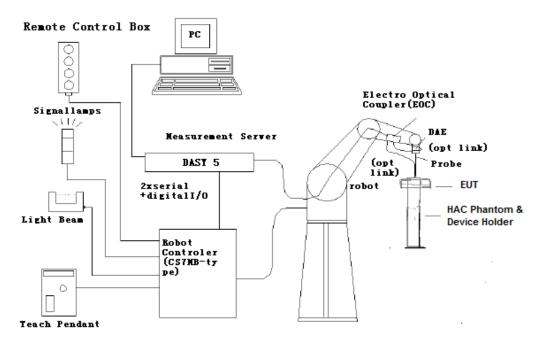


Fig. 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



6.2 Probe Specification

E-Field Probe Description

Construction One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%,

k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity ± 0.2 dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements

Fast automatic scanning in phantoms



[ER3DV6]



6.3Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: $370 \times 370 \times 370 \text{ mm}$).

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field $<\pm 0.5$ dB.

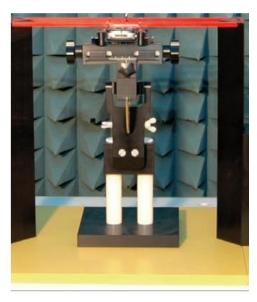


Fig. 2 HAC Phantom & Device Holder

6.4Robotic System Specifications

Specifications

Positioner: Stäubli Unimation Corp. Robot Model: RX160L

Repeatability: ±0.02 mm

No. of Axis: 6

Data Acquisition Electronic (DAE) System

Cell Controller

Processor: Intel Core2 Clock Speed: 1.86GHz

Operating System: Windows XP

Data Converter

Features: Signal Amplifier, multiplexer, A/D converter, and control logic

Software: DASY5 software

Connecting Lines: Optical downlink for data and status info.

Optical uplink for commands and clock



7 EUT ARRANGEMENT

7.1 WD RF Emission Measurements Reference and Plane

Figure 4 illustrates the references and reference plane that shall be used in the WD emissions measurement.

- The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.
- The grid is centered on the audio frequency output transducer of the WD (speaker or T-coil).
- The grid is located by reference to a reference plane. This reference plane is the planar area that contains the highest point in the area of the WD that normally rests against the user's ear
- •The measurement plane is located parallel to the reference plane and 15 mm from it, out from the phone. The grid is located in the measurement plane.

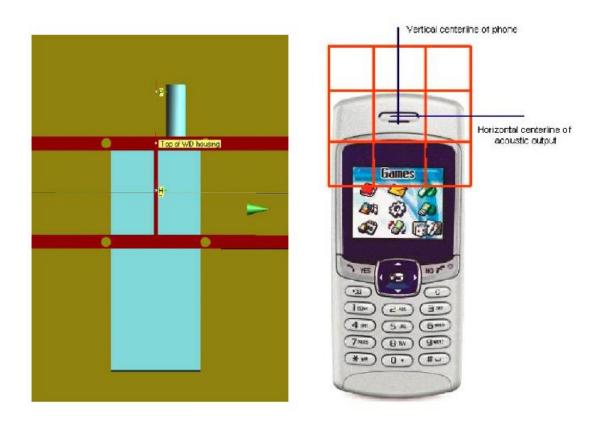


Fig. 3 WD reference and plane for RF emission measurements



8 SYSTEM VALIDATION

8.1 Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical output. Position the E-field probes so that:

- •The probes and their cables are parallel to the coaxial feed of the dipole antenna
- •The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions
- The center point of the probe element(s) are 15 mm from the closest surface of the dipole elements.

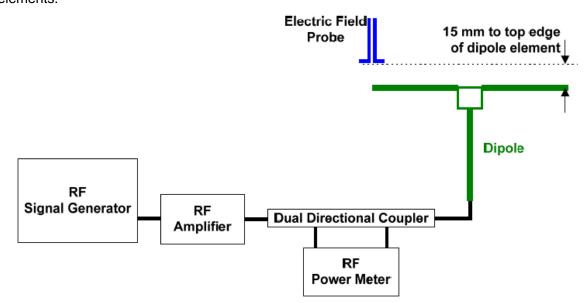


Fig. 4 Dipole Validation Setup

8.2 Validation Result

E-Field Scan						
Mode	Frequency (MHz)	Input Power (mW)	Measured ¹ Value(dBV/m)	Target ² Value(dBV/m)	Deviation ³ (%)	Limit ⁴ (%)
CW	835	100	40.55	40.91	-4.06	±25
CW	1880	100	39.45	39.01	5.20	±25

Notes:

- 1. Please refer to the attachment for detailed measurement data and plot.
- 2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
- 3. Deviation (%) = 100 * (Measured value minus Target value) divided by Target value.
- 4. ANSI C63.19 requires values within \pm 25% are acceptable, of which 12% is deviation and 13% is measurement uncertainty. Values independently validated for the dipole actually used in the measurements should be used, when available.



9 Evaluation of MIF

9.1 Introduction

The MIF (Modulation Interference Factor) is used to classify E-field emission to determine Hearing Aid Compatibility (HAC). It scales the power-averaged signal to the RF audio interference level and is characteristic to a modulation scheme. The HAC standard preferred "indirect" measurement method is based on average field measurement with separate scaling by the MIF. With an Audio Interference Analyzer (AIA) designed by SPEAG specifically for the MIF measurement, these values have been verified by practical measurements on an RF signal modulated with each of the waveforms. The resulting deviations from the simulated values are within the requirements of the HAC standard.

The AIA (Audio Interference Analyzer) is an USB powered electronic sensor to evaluate signals in the frequency range 698MHz - 6 GHz. It contains RMS detector and audio frequency circuits for sampling of the RF envelope.

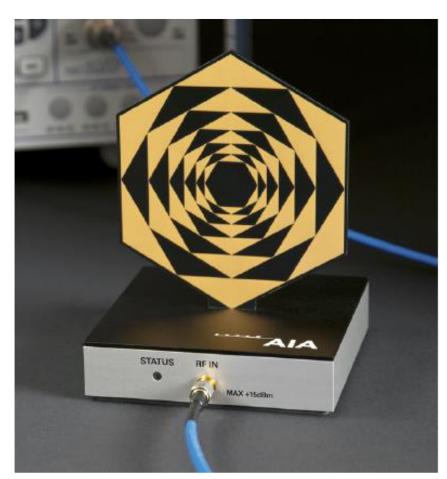


Fig. 5 AIA Front View



9.2 MIF measurement with the AIA

The MIF is measured with the AIA as follows:

- 1. Connect the AIA via USB to the DASY5 PC and verify the configuration settings.
- 2. Couple the RF signal to be evaluated to an AIA via cable or antenna.
- 3. Generate a MIF measurement job for the unknown signal and select the measurement port and timing settings.
- 4. Document the results via the post processor in a report.

9.3 Test equipment for the MIF measurement

No.	Name	Туре	Serial Number	Manufacturer
01	Signal Generator	E4438C	MY49071430	Agilent
02	AIA	SE UMS 170 CB	1029	SPEAG
03	BTS	E5515C	MY50263375	Agilent

9.4 Test signal validation

The signal generator (E4438C) is used to generate a 1GHz signal with different modulation in the below table based on the ANSI C63.19-2011. The measured MIF with AIA are compared with the target values given in ANSI C63.19-2011 table D.3, D.4 and D5.

Pulse modulation	Target MIF	Measured MIF	Deviation
0.5ms pulse, 1000Hz repetition rate	-0.9 dB	-0.9 dB	0 dB
1ms pulse, 100Hz repetition rate	+3.9 dB	+3.7 dB	0.2 dB
0.1ms pulse, 100Hz repetition rate	+10.1 dB	+10.0 dB	0.1 dB
10ms pulse, 10Hz repetition rate	+1.6 dB	+1.7 dB	0.1 dB
Sine-wave modulation	Target MIF	Measured MIF	Deviation
1 kHz, 80% AM	-1.2 dB	-1.3 dB	0.1 dB
1 kHz, 10% AM	-9.1 dB	-9.0 dB	0.1 dB
1 kHz, 1% AM	-19.1 dB	-18.9 dB	0.2 dB
100 Hz, 10% AM	-16.1 dB	-16.0 dB	0.1 dB
10 kHz, 10% AM	-21.5 dB	-21.6 dB	0.1 dB
Transmission protocol	Target MIF	Measured MIF	Deviation
GSM; full-rate version 2; speech codec/handset low	+3.5 dB	+3.47 dB	0.03 dB
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB	-19.8 dB	0.2 dB
CDMA; speech; SO3; RC3; full frame rate; 8kEVRC	-19.0 dB	-19.1 dB	0.1 dB
CDMA; speech; SO3; RC1; 1/8 th frame rate; 8kEVRC	+3.3 dB	+3.44 dB	0.14 dB



9.5 DUT MIF results

Typical MIF levels in ANSI C63.19-2011				
Transmission protocol	Modulation interference factor			
GSM; full-rate version 2; speech codec/handset low	+3.5 dB			
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, QPSK)	-15.63 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-9.76 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, 64QAM)	-9.93 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, QPSK)	-1.62 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-1.44 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, 64QAM)	-1.54 dB			

Measured MIF levels					
Band	Channel	Modulation interference factor (dB)			
	251	3.42			
GSM 850	190	3.47			
	128	3.49			
	810	3.48			
GSM 1900	661	3.46			
	512	3.45			
	4458	-23.14			
W850	4407	-21.53			
	4357	-22.61			
	9938	-23.65			
W1900	9800	-22.62			
	9662	-23.54			
	1738	-23			
W1700	1637	-22.95			
	1537	-23.38			
LTE D 10	19100	-14.4			
LTE Band2 QPSK	18900	-14.63			
QI OIL	18700	-14.02			
LTE D. JE	20600	-13.67			
LTE Band5 QPSK	20525	-14.46			
QI OIL	20450	-14.15			
1.TE D. 140	23130	-14.82			
LTE Band12 QPSK	23095	-13.98			
QI OIL	23060	-14.38			
LTE Band13 QPSK	23230	-14.19			
LTE Band66	132572	-14.03			
QPSK	132322	-14.28			



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	132072	-13.78
1.TE D 174	133372	-13.33
LTE Band71 QPSK	133297	-14.06
QI OIL	133222	-13.55
1.TE D 10	19100	-9.92
LTE Band2 16QAM	18900	-10.54
IOQAW	18700	-10.7
	20600	-9.85
LTE Band5 16QAM	20525	-10.16
100/11/1	20450	-11.06
LTE D 140	23130	-9.89
LTE Band12 16QAM	23095	-11.23
100/11/1	23060	-10.43
LTE Band13 16QAM	23230	-10.17
LTE D 100	132572	-10.57
LTE Band66 16QAM	132322	-10.48
100/1111	132072	-10.02
	133372	-10.65
LTE Band71 16QAM	133297	-10.03
109/11/1	133222	-10.85
2.4GHz	11	-10.22
802.11g	6	-9.78
6M	1	-9.82



10 Evaluation for low-power exemption

10.1 Product testing threshold

There are two methods for exempting an RF air interface technology from testing. The first method requires evaluation of the MIF for the worst-case operating mode. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is \leq 17 dBm for any of its operating modes. The second method does not require determination of the MIF. The RF emissions testing exemption shall be applied to an RF air interface technology in a device whose peak antenna input power, averaged over intervals \leq 50 $\,\mu$ s20, is \leq 23 dBm. An RF air interface technology that is exempted from testing by either method shall be rated as M4.

The first method is used to be exempt from testing for the RF air interface technology in this report.

10.2 Conducted power

Band	Average power (dBm)	MIF (dB)	Sum (dBm)
GSM 850	32.7	3.49	36.19
GSM 1900	30.08	3.48	33.56
WCDMA 850	22.83	-21.53	1.3
WCDMA 1700	22.98	-22.95	0.03
WCDMA 1900	23.99	-22.62	1.37
LTE B2	23.68	-9.92	13.76
LTE B5	23.42	-9.85	13.57
LTE B12	23.64	-9.89	13.75
LTE B13	23.19	-10.17	13.02
LTE B66	23.87	-10.02	13.85
LTE B71	23.81	-10.03	13.78
WiFi-2.4G	20.47	-9.78	10.69

10.3 Conclusion

According to the above table, the sums of average power and MIF for UMTS, LTE and WiFi are less than 17dBm. So it is only measured for GSM bands. The UMTS, LTE and WiFi are exempt from testing and rated as M4.



11 RF TEST PROCEDUERES

The evaluation was performed with the following procedure:

- 1) Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2) Position the WD in its intended test position. The gauge block can simplify this positioning.
- 3) Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4) The center sub-grid shall centered on the center of the T-Coil mode axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5) Record the reading.
- 6) Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7) Identify the five contiguous sub-grids around the center sub-grid whose maximum reading is the lowest of all available choices. This eliminates the three sub-grids with the maximum readings. Thus, the six areas to be used to determine the WD's highest emissions are identified.
- 8) Identify the maximum field reading within the non-excluded sub-grids identified in Step 7)
- 9) Evaluate the MIF and add to the maximum steady-state rms field-strength reading to obtain the RF audio interference level..
- Compare this RF audio interference level with the categories and record the resulting WD category rating.



12 Measurement Results (E-Field)

Channel	AWF	Measured Value (V/m)	Power Drift (dB)	Category M?	MIF
	•		GSM 850		
251	0	37.74	-0.04	M4	3.40
190	0	38.01	-0.03	M4	3.49
128	0	38.99	-0.06	M4	3.43
	PCS 1900				
810	0	29.84	0.08	M4	3.37
661	0	29.87	0.04	M4	3.33
512	0	29.88	0.03	M4	3.45



13 ANSIC 63.19-2011 LIMITS

WD RF audio interference level categories in logarithmic units

Emission categories	< 960 MHz		
	E-field er	missions	
Category M1	50 to 55	dB (V/m)	
Category M2	45 to 50	dB (V/m)	
Category M3	40 to 45	dB (V/m)	
Category M4	< 40	dB (V/m)	
Emission categories	>960 MHz		
	E-field e	missions	
Category M1	40 to 45	dB (V/m)	
Category M2	35 to 40	dB (V/m)	
Category M3	30 to 35	dB (V/m)	
Category M4	< 30	dB (V/m)	



14 MEASUREMENT UNCERTAINTY

No.	Error source	Туре	Uncertainty Value(%)	Prob. Dist.	k	c _i E	Standard Uncertainty (%) $u_i^{'}$ (%)E	Degree of freedom V _{eff} or <i>v</i> i
Meas 1	Measurement System							
	Probe Calibration	В	5.	N	1	1	5.1	∞
2	Axial Isotropy	В	4.7	R	$\sqrt{3}$	1	2.7	∞
3	Sensor Displacement	В	16.5	R	$\sqrt{3}$	1	9.5	∞
4	Boundary Effects	В	2.4	R	$\sqrt{3}$	1	1.4	∞
5	Linearity	В	4.7	R	$\sqrt{3}$	1	2.7	∞
6	Scaling to Peak Envelope Power	В	2.0	R	$\sqrt{3}$	1	1.2	∞
7	System Detection Limit	В	1.0	R	$\sqrt{3}$	1	0.6	∞
8	Readout Electronics	В	0.3	N	1	1	0.3	∞
9	Response Time	В	0.8	R	$\sqrt{3}$	1	0.5	∞
10	Integration Time	В	2.6	R	$\sqrt{3}$	1	1.5	∞
11	RF Ambient Conditions	В	3.0	R	$\sqrt{3}$	1	1.7	∞
12	RF Reflections	В	12.0	R	$\sqrt{3}$	1	6.9	∞
13	Probe Positioner	В	1.2	R	$\sqrt{3}$	1	0.7	∞
14	Probe Positioning	А	4.7	R	$\sqrt{3}$	1	2.7	∞
15	Extra. And Interpolation	В	1.0	R	$\sqrt{3}$	1	0.6	∞
Test Sample Related								
16	Device Positioning Vertical	В	4.7	R	$\sqrt{3}$	1	2.7	∞
17	Device Positioning Lateral	В	1.0	R	$\sqrt{3}$	1	0.6	∞
18	Device Holder and Phantom	В	2.4	R	$\sqrt{3}$	1	1.4	∞
19	Power Drift	В	5.0	R	$\sqrt{3}$	1	2.9	∞



20	AIA measurement	В	12	R	$\sqrt{3}$	1	6.9	∞
Pha	Phantom and Setup related							
21	Phantom Thickness	В	2.4	R	$\sqrt{3}$	1	1.4	8
Coml	Combined standard uncertainty(%) 16.2							
Expanded uncertainty (confidence interval of 95 %)		$u_e = 2u_c$	Z	k=:	2	32.4		

15 MAIN TEST INSTRUMENTS

No.	Name	Туре	Serial Number	Calibration Date	Valid Period
01	Signal Generator	E4438C	MY49071430	January 2, 2018	One Year
02	Power meter	NRVD	102083	November 01, 2017	One year
03	Power sensor	NRV-Z5	100542	November 01, 2017	One year
04	Amplifier	60S1G4	0331848	No Calibration Requested	
05	AIA	SE UMS 170 CB	1029	No Calibration Requested	
06	E-Field Probe	EF3DV3	4060	June 12, 2018	One year
09	DAE	SPEAG DAE4	1555	August 20, 2018	One year
80	HAC Dipole	CD835V3	1023	August 28, 2018	One year
09	HAC Dipole	CD1880V3	1018	August 28, 2018	One year
10	BTS	E5515C	MY50263375	January 23, 2018	One year
11	BTS	CMW500	166370	August 23, 2018	One year

16 CONCLUSION

The HAC measurement indicates that the EUT complies with the HAC limits of the ANSIC63.19-2011. The total M-rating is **M4.**

END OF REPORT BODY



ANNEX A TEST LAYOUT



Picture A1:HAC RF System Layout



ANNEX B TEST PLOTS

HAC RF E-Field GSM 850 High

Date: 2018-10-11

Electronics: DAE4 Sn1555

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV3 - SN4060;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 70.52 V/m; Power Drift = -0.04 dB

Applied MIF = 3.42 dB

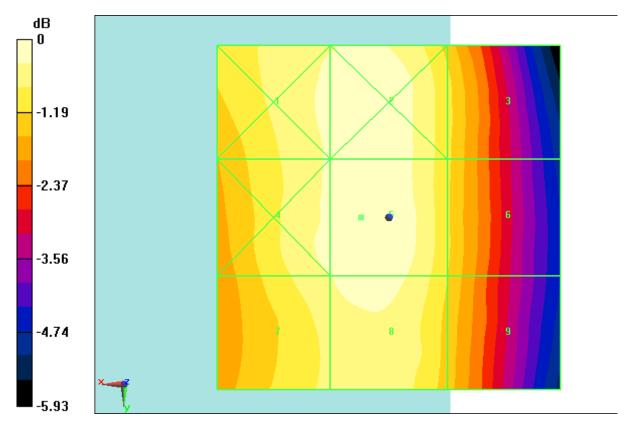
RF audio interference level = 37.74 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
37.45 dBV/m	37.62 dBV/m	36.69 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
37.5 dBV/m	37.74 dBV/m	36.65 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
37.34 dBV/m	37.56 dBV/m	36.56 dBV/m





0 dB = 77.07 V/m = 37.74 dBV/m

Fig B.1 HAC RF E-Field GSM 850 High



HAC RF E-Field GSM 850 Middle

Date: 2018-10-11

Electronics: DAE4 Sn1555

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Probe: ER3DV3 - SN4060;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 70.71 V/m; Power Drift = -0.03 dB

Applied MIF = 3.47 dB

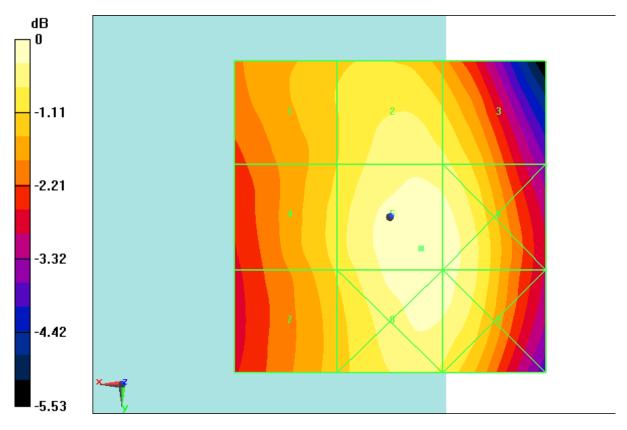
RF audio interference level = 38.01 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
36.92 dBV/m	37.54 dBV/m	37.38 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
37.1 dBV/m	38.01 dBV/m	37.89 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
36.96 dBV/m	37.93 dBV/m	37.85 dBV/m





0 dB = 79.49 V/m = 38.01 dBV/m

Fig B.2 HAC RF E-Field GSM 850 Middle



HAC RF E-Field GSM 850 Low

Date: 2018-10-11

Electronics: DAE4 Sn1555

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV3 - SN4060;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 72.41 V/m; Power Drift = -0.06 dB

Applied MIF = 3.49 dB

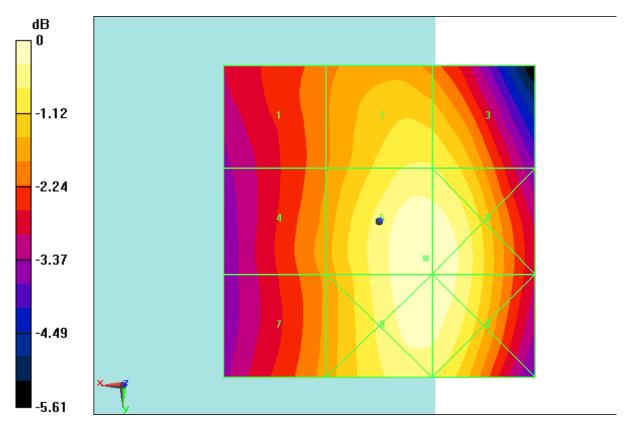
RF audio interference level = 38.99 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
37.09 dBV/m	38.31 dBV/m	38.28 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
37.37 dBV/m	38.99 dBV/m	38.97 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
37.31 dBV/m	38.95 dBV/m	38.94 dBV/m





0 dB = 88.98 V/m = 38.99 dBV/m

Fig B.3 HAC RF E-Field GSM 850 Low



HAC RF E-Field GSM 1900 High

Date: 2018-10-12

Electronics: DAE4 Sn1555

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV3 - SN4060;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 19.95 V/m; Power Drift = 0.08 dB

Applied MIF = 3.48 dB

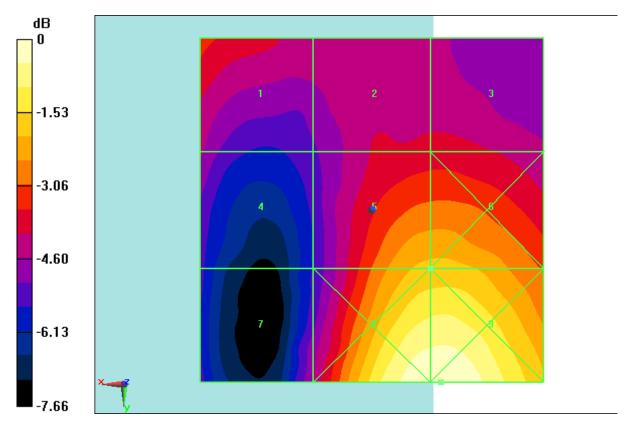
RF audio interference level = 29.84 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
28.35 dBV/m	27.86 dBV/m	27.87 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
27.29 dBV/m	29.84 dBV/m	29.87 dBV/m
Grid 7 M4	Grid 8 M3	Grid 9 M3
27.2 dBV/m	31.69 dBV/m	31.72 dBV/m





0 dB = 38.57 V/m = 31.72 dBV/m

Fig B.4 HAC RF E-Field GSM 1900 High



HAC RF E-Field GSM 1900 Middle

Date: 2018-10-12

Electronics: DAE4 Sn1555

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Probe: ER3DV3 - SN4060;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 19.85 V/m; Power Drift = 0.04 dB

Applied MIF = 3.46 dB

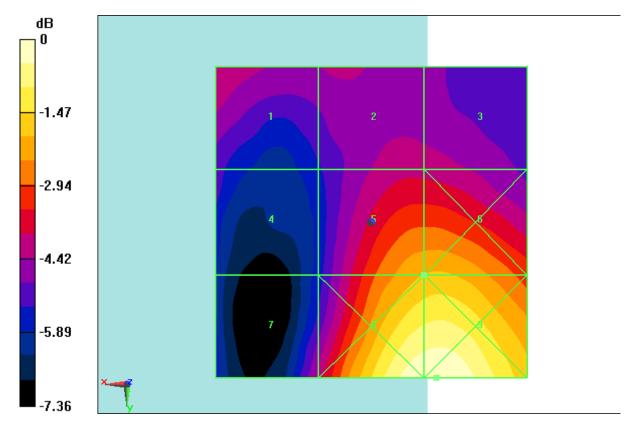
RF audio interference level = 29.87 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.91 dBV/m	27.76 dBV/m	27.72 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
26.7 dBV/m	29.87 dBV/m	29.93 dBV/m
Grid 7 M4	Grid 8 M3	Grid 9 M3
27.61 dBV/m	31.74 dBV/m	31.8 dBV/m





0 dB = 38.89 V/m = 31.80 dBV/m

Fig B.5 HAC RF E-Field GSM 1900 Middle



HAC RF E-Field GSM 1900 Low

Date: 2018-10-12

Electronics: DAE4 Sn1555

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV3 - SN4060;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 20.79 V/m; Power Drift = 0.03 dB

Applied MIF = 3.45 dB

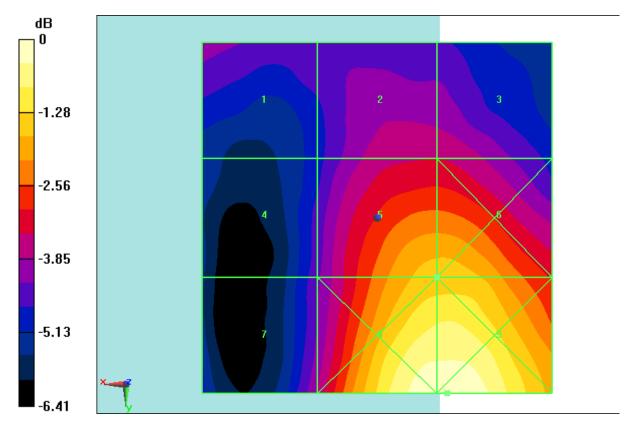
RF audio interference level = 29.88 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.3 dBV/m	27.97 dBV/m	27.97 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
27.03 dBV/m	29.88 dBV/m	29.88 dBV/m
Grid 7 M4	Grid 8 M3	Grid 9 M3
27.6 dBV/m	31.34 dBV/m	31.37 dBV/m





0 dB = 37.04 V/m = 31.37 dBV/m

Fig B.6 HAC RF E-Field GSM 1900 Low



ANNEX C SYSTEM VALIDATION RESULT

E SCAN of Dipole 835 MHz

Date: 2018-10-11

Electronics: DAE4 Sn1555

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon r = 1$; $\rho = 1000$ kg/m3 Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Probe: ER3DV3 - SN4060;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 15mm/Hearing Aid Compatibility Test (41x361x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 106.54 V/m; Power Drift = -0.03 dB

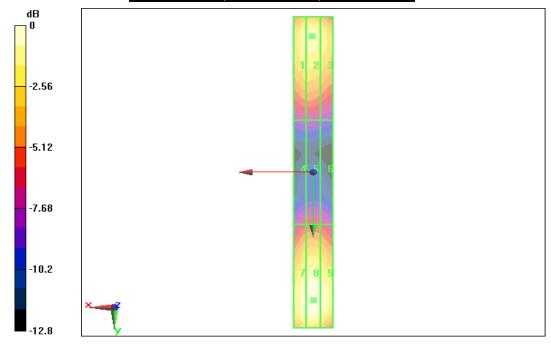
Applied MIF = 0.00 dB

RF audio interference level = 40.55 dBV/m

Emission category: M3

MIF scaled E-field

Grid 1 M3	Grid 2M3	Grid 3M3
40.39 dBV/m	40.51 dBV/m	40.33 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
35.93 dBV/m	36.04 dBV/m	35.88 dBV/m
Grid 7 M3	Grid 8 M3	Grid 9 M3
40.34 dBV/m	40.55 dBV/m	40.46 dBV/m



0 dB = 40.55 dBV/m



E SCAN of Dipole 1880 MHz

Date: 2018-10-12

Electronics: DAE4 Sn1555

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Probe: ER3DV3 - SN4060;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 93.86 V/m; Power Drift = 0.02 dB

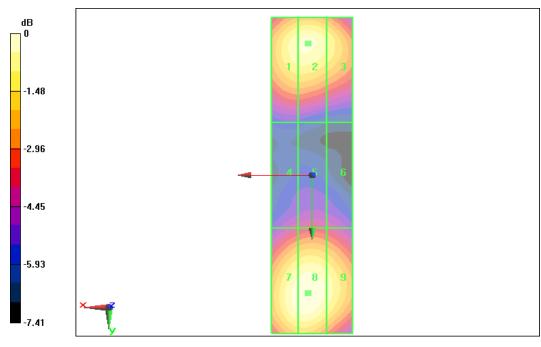
Applied MIF = 0.00 dB

RF audio interference level = 39.45 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1 M2	Grid 2 M2	Grid 3 M2
39.21 dBV/m	39.45 dBV/m	39.36 dBV/m
Grid 4M2	Grid 5M2	Grid 6M2
37.22 dBV/m	37.36 dBV/m	37.26 dBV/m
Grid 7M2	Grid 8M2	Grid 9 M2
38.78 dBV/m	39.05dBV/m	38.98 dBV/m



0 dB = 39.45 dBV/m



ANNEX D PROBE CALIBRATION CERTIFICATE

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

Client

CTTL-BJ (Auden)

Certificate No: EF3-4060_Jun18

CALIBRATION CERTIFICATE

Object

EF3DV3 - SN:4060

Calibration procedure(s)

QA CAL-02.v8, QA CAL-25.v6

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

June 12, 2018

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: S5277 (20x)	04-Apr-18 (No. 217-02682)	Apr-19
Reference Probe ER3DV6	SN: 2328	10-Oct-17 (No. ER3-2328_Oct17)	Oct-18
DAE4	SN: 789	2-Aug-17 (No. DAE4-789_Aug17)	Aug-18
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-18)	In house check: Jun-20
Network Analyzer HP 8753E	SN: US37390585	18-Oct-01 (in house check Oct-17)	In house check: Oct-18

Calibrated by:

Mame
Function
Signature

Michael Weber
Laboratory Technician

Approved by:

Katja Pokovic
Technical Manager

Issued: June 12, 2018

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: EF3-4060_Jun18

Page 1 of 39



No.I18Z61787-SEM02 Page 42 of 67

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
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Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossary:

NORMx,y,z sensitivity in free space diode compression point

CF crest factor (1/duty_cycle) of the RF signal A, B, C, D modulation dependent linearization parameters

Polarization φ φ rotation around probe axis

Polarization 9 9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

 IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005

b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.0, November 2013

Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- NORM(f)x,y,z = NORMx,y,z * frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

Certificate No: EF3-4060_Jun18 Page 2 of 39



Probe EF3DV3

SN:4060

Manufactured: Calibrated:

March 13, 2018 June 12, 2018

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

Certificate No: EF3-4060_Jun18

Page 3 of 39

June 12, 2018 EF3DV3 - SN:4060

DASY/EASY - Parameters of Probe: EF3DV3 - SN:4060

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)	
Norm $(\mu V/(V/m)^2)$	0.76	0.71	1.33	± 10.1 %	
DCP (mV) ^B	95.7	94.8	94.0		

Modulation Calibration Parameters

UID	Communication System Name		A dB	B dB√μV	С	D dB	VR mV	Unc ^E (k=2)
0	CW	X	0.0	0.0	1.0	0.00	178.2	±2.2 %
		Y	0.0	0.0	1.0		166.5	
		Z	0.0	0.0	1.0		136.4	

Note: For details on UID parameters see Appendix.

Sensor Model Parameters

	C1	C2	α	T1	T2	T3	T4	T5	Т6
	fF	fF	V ⁻¹	ms.V ⁻²	ms.V ⁻¹	ms	V-2	V ⁻¹	
X	37.27	249.6	37.86	6.092	0.115	4.959	0.368	0.148	1.000
Υ	36.09	241.8	37.76	8.234	0.000	5.006	0.000	0.039	1.010
Z	34.42	234.1	38.89	6.204	0.000	4.988	0.000	0.063	1.006

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: EF3-4060_Jun18

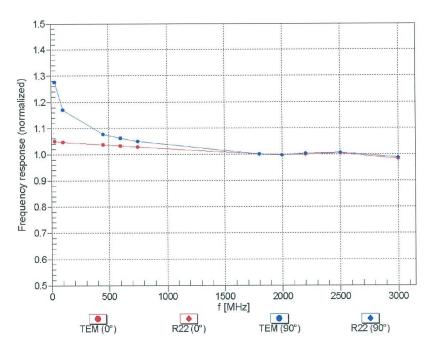
B Numerical linearization parameter: uncertainty not required.
E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.



EF3DV3 - SN:4060

June 12, 2018

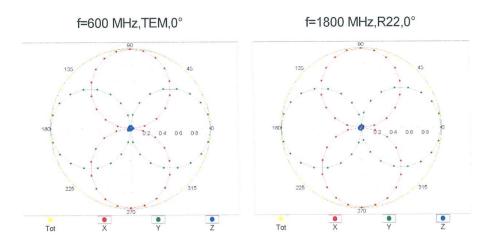
Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



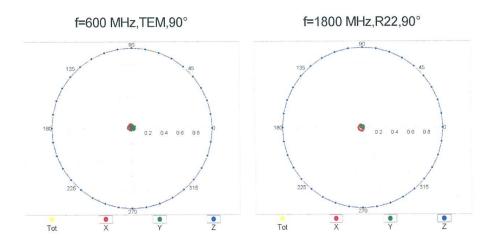
Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)



Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



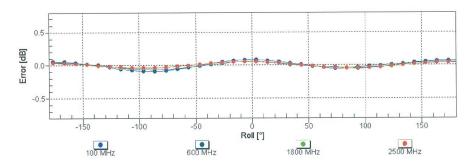
Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$



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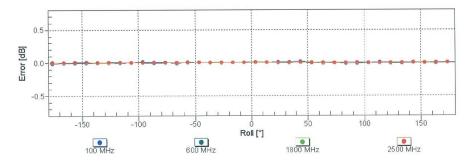


Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$

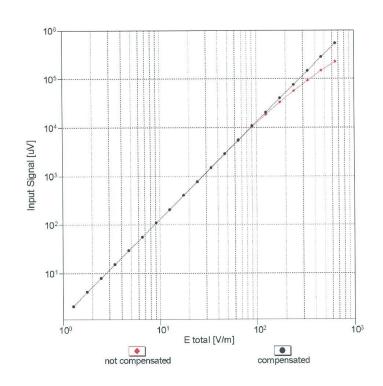


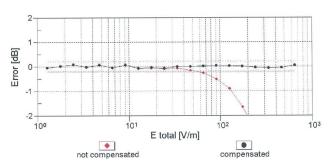
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

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Dynamic Range f(E-field) (TEM cell , f = 900 MHz)



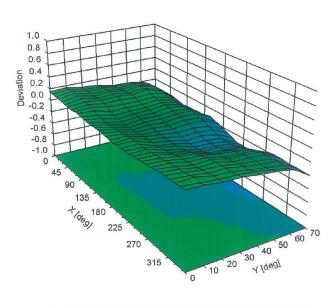


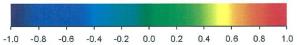
Uncertainty of Linearity Assessment: ± 0.6% (k=2)

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Deviation from Isotropy in Air Error (ϕ, ϑ) , f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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EF3DV3 - SN:4060

June 12, 2018

DASY/EASY - Parameters of Probe: EF3DV3 - SN:4060

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	143.6
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	335 mm
Probe Body Diameter	12 mm
Tip Length	25 mm
Tip Diameter	4 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

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